

Prototype Information

Automotive Dual High Side TMOS Driver

The MC33285 is a dual high side TMOS driver designed for use in the harsh automotive switching applications.

The purpose of the MC33285 is to drive two power n-channel FETs in a high side application with an inductive load. The application in an automotive environment requires the capability of withstanding high voltages and load dump transients. The MC33285 is able to withstand reverse battery conditions at selected pins.

It protects the n-channel power FET on OUT1 under over current condition. This device has one input to control both stages on or off.

- Temperature Range from -40°C to +125°C
- PWM Capability
- Power TMOS # 1 Over-Current and Short-Circuit Protection
- Voltage Range 7V to 40V
- Reverse Battery Conditions at Selected Pins
- Extended Temperature Range from -40°C to 125°C
- Load Dump Protected
- Over Voltage Detection and Activation of OUT2 during Overvoltage
- Single Input Control for both Output Stages
- Capacitor Value of 100nF Connected to Pin CP

MC33285

**HIGH SIDE
TMOS DRIVER**

**SILICON MONOLITHIC
INTEGRATED CIRCUIT**

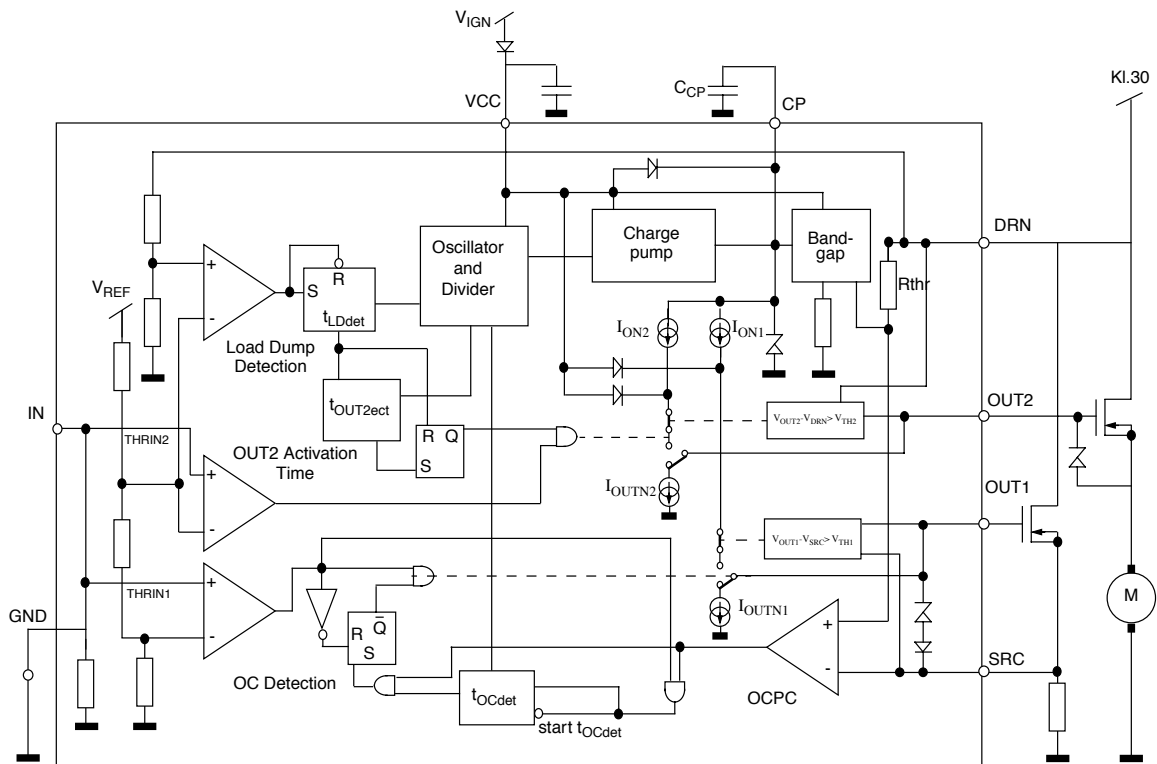


D SUFFIX
PLASTIC PACKAGE
CASE 751-02
S0-8

PIN CONNECTIONS

SRC	1	0	8	IN
OUT1	2		7	GND
DRN	3		6	V _{CC}
OUT2	4		5	CP

Block Diagram And Typical Application



**MAXIMUM RATING
ELECTRICAL RATINGS**

Rating	Symbol	Value	Unit
Maximum voltage at pins OUT1 OUT2	V_{OUT}	$V_{VCC} + 20$	V
Maximum voltage at pin CP	V_{CP}	60	V
Input voltage V_i at DRN and SCR	V_i	-25 to 40	V
Input voltage at pin VCC	V_{VCC}	-2 to 40	V
Input Voltage at pin IN condition : $-2V < V_{VCC} < 40V$	V_{IN}	-2 to V_{VCC}	V
Operatinnal voltage V_{VCC} at pin VCC	V_{VCC}	7 to V_i	V

THERMAL RATINGS

Rating	Symbol	Value	Unit
Storage Temperature	T_{stg}	-40 to +150	°C
Operating ambient temperature	T_a	-40 to +125	°C

ELECTRICAL CHARACTERISTICS. (T_A from -40°C to +125°C, V_{CC} from 7V to 20V, unless otherwise noted)

SRC pin 1

Characteristic	Symbol	Min	Typ	Max	Unit
Leakage Current	I_{leak_src}	-10		10	μA

OUT 1 pin 2

Operating Current ($7V < V_{DRN} < 20V$)	I_{DRN}			1	mA
Leakage current ($0V < V_{DRN} < 20V$, $V_{VCC} < 4V$)	I_{leak_DRN}			10	μA

DRN pin 3

Output On Voltage. Charge Pump ON	V_{on}			$V_{CC}+15$	V
Output Off Voltage. Charge Pump OFF	V_{off}			0.9	V
Turn off current - with NO Over Vds Condition, and $V_{out} > 0.5V$ - with Over Vds Condition, and $V_{out} > 0.5V$	I_{outn} I_{outw}	70 5	110 10	150 15	μA
Turn On Time - $C_I = 25nF$, $7V < V_{CC} < 10V$, $V_{out} > V_{CC}+7$ - $C_I = 25nF$, $10V < V_{CC} < 20V$, $V_{out} > V_{CC}+10$	t_{on}			1 1	ms

OUT2 pin 4

Supply Voltage Range	V_{CC}	7		20	V
Quiescent Supply Current - at $V_{CC} = 7V$ - at $V_{CC} = 20V$	I_{CC}		1.8 2.8	5 5	mA

CP pin 5

Output Voltage @ $I = 1mA$	V_{ol}			1.5	V
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VCC pin 6

Input Low Voltage	V_{il}			1.5	V
Input High Voltage	V_{ih}	3.5			V
Input Hysteresis	V_{hys}	0.8			V
Input Pull Down Resistor. $V_{in} > 11V$	R_{in}	20	36	100	kΩ
Open Input Voltage	V_{iop}			1	V

IN pin 8

Timer Current	I_{time}	7.8	10	12.2	μA
On Threshold	V_{hth}	5.2	5.5	5.8	V

Off Threshold	V _{lth}	2.47	2.75	3.03	V
Discharge Current @ V _{time} = 5V	I _{disch}	2		10	mA
Saturation Voltage @ I _{time} = 1mA	V _{sat}			0.4	V

Turn On Characteristics

The power FETs are turned on by charging their gate capacities with a current flowing out of pin OUT1 and OUT2. The values of table 10.2-1 are guaranteed. For these values it is not necessary to switch OUT1 and OUT2 at the same time.

They are measured with the test circuit and load conditions specified in Chapter 10.1.

- test condition : V_{IN} : ramp 0V to 2.5V or 2.5V to 5V.

Figure 1. Turn-on Behaviour of the MC33285

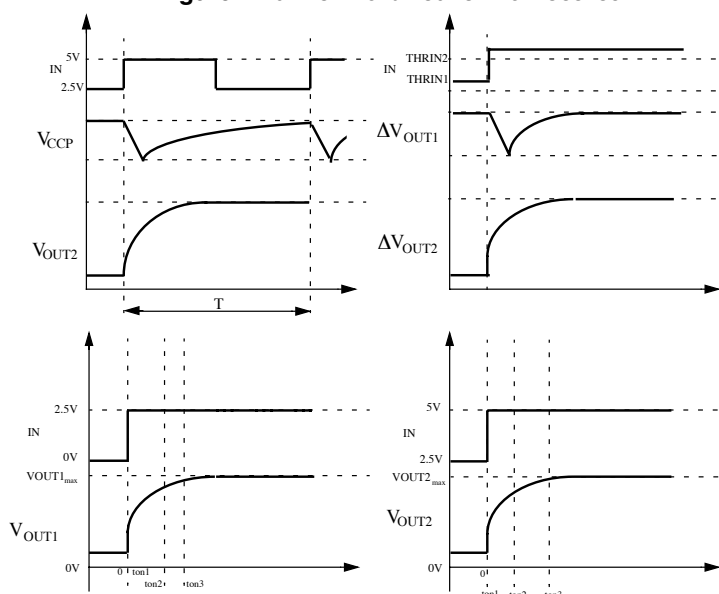


Figure D. Turn on behaviour

Voltage V _{VCC}	Minimum V _{OUT1,OUT2} after t _{on1} = 100μsec	Minimum V _{OUT1,OUT2} after t _{on1} = 1.0msec	Minimum V _{OUT1,OUT2} after t _{on1} = 1.5msec
7V < V _{VCC} < 10V	V _{VCC} - 0.7V	V _{VCC} + 5.95V	V _{VCC} + 7V
10V < V _{VCC} < 20V	V _{VCC} - 0.7V	V _{VCC} + 9.35V	V _{VCC} + 11V
20V < V _{VCC} < 40V	V _{VCC} - 0.7V		

The output voltages at OUT1 and OUT2 are limited by controlling the current sources I_{on1}, I_{on2} to avoid current flowing through the external or the internal zener diode. If the threshold voltage is reached, the current sources are turned off.

- threshold V_{TH1} for OUT1 output voltage control :
14V < V_{TH1} < 16V condition : (V_{OUT1} - V_{SRC}) < V_{TH1}
- threshold V_{TH2} for OUT2 output voltage control :
13V < V_{TH2} < 15V condition : (V_{OUT2} - V_{DRN}) < V_{TH2}

Turn off characteristics

The power FETs on OUT1 and OUT2 are turned off by discharging the gate capacity with the constant discharge current I_{OUToff}.

- discharge current I_{OUTxoff} : I_{OUTxoff} = 110μA
- condition : V_{OUTx} > 0.5V (V_{IN} < V_{THRxiN})
- Test conditions for switching off the power FETs :
 1. IN open
 2. Stages disabled via pin IN
 3. Stage OUT1 disabled by an over current error

FUNCTIONAL DESCRIPTION

Introduction

The MC33285 contains only one charge pump for two outputs. The outputs OUT1 and OUT2 are switched on and off by the input IN. There are three ways to control the outputs: OUT1 can be switched alone, they can be switched together or OUT2 can be switched when OUT1 is already on. In the last case, the voltage drop on OUT1 when charging OUT2 is limited.

The external capacitor C_{CP} connected to pin CP is used to store the charge continuously delivered by the charge pump. The voltage on this pin is limited to a maximum value V_{CPmax} . Both outputs are sourced with a constant current from C_{CP} to switch them on. In addition, the gates of the power FETs are precharged from VCC to prevent C_{CP} from being discharged by a voltage on OUT1 or OUT2 which is still lower than V_{VCC} . The values of the output voltages are limited to $V_{OUT1max}$ and $V_{OUT2max}$.

The power FET on OUT1 is protected against an exceeded gate-source voltage by an internal zener diode, which also provides protection against reverse battery conditions.

Channel 1 allows to protect the n-channel power FET on OUT1 under over current condition. The drain-source voltage of the FET on OUT1 will be checked, if the channel 1 is switched on. The internal error voltage threshold determines the maximum drain-source voltage that allows the power FET to stay in the on state. If the measured drain-source voltage exceeds the internal error voltage threshold, the output of the Over Current Protection Comparator (OCPC) is enabled. If the output of the OCPC is active longer than t_{OCdet} , the output OUT1 is switched off.

After switching off the power FET on OUT1 by an over current condition, the power FET can only be turned on again by the input IN. For more details see Figure 6-1.

When switching off the power FETs their gate capacities are discharged by a constant current I_{OUToff} .

If the input IN is disconnected, the MC33285 outputs OUT1 and OUT2 is in the off state.

If overvoltage occurs on pin DRN for a time period longer than t_{LDdet} , then OUT2 is switched on for the time $t_{OUT2act}$. In overvoltage condition OUT1 is off if IN is below THR1.

Internal Zener Diode

An on-chip zener diode is placed between OUT1 and SRC. Design guarantee that $V_Z > V_{TH1}$.

- zener clamping voltage between OUT1 and SRC :
 $V_{TH1} < V_Z < 20V$

PWM capability

The CPIC2 is PWM capable on OUT2. The loss of charge on C_{cp} when switching on OUT2 is refreshed until the start on the next PWM cycle to a value which is sufficient to guarantee the specified turn on behaviour.

The PWM capability is measured with a test circuit and load conditions

- PWM cycle : period $T = 20ms$; OUT2 is switched on from 10% to 90% of T .

- Test condition : V_{IN} : ramps 2.5V to 5V according to PWM cycle defined above.


Crosstalk between OUT1 and OUT2

If output OUT2 is switched on while OUT1 is already on, the voltage drop that occurs on OUT1 is limited. C_{CP} is not allowed to be sourced by OUT1.

- Voltage drop on OUT1 :

$10V < V_{VCC} < 20V$: OUT1 not below $V_{VCC} + 9V$

$7V < V_{VCC} < 20V$: OUT1 not below $V_{VCC} + 5V$

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